THE DATASHEET OF

TS86436P

www.win-source.net 0086-755-83957316

TS86436P – SP4T 200W Average Power Switch 30 MHz to 1.32 GHz

1.0 Features

- Low insertion loss: 0.09dB @ 30 MHz
- High isolation: 70 dB @ 30 MHz, 36 dB @ 1 GHz
- 200W CW Power, 350Wp Peak Power
- No external DC blocking capacitors on RF lines
- All RF ports OFF state
- Versatile 2.6-5.25V power supply
- Operating frequency: 30 MHz to 1320 MHz



Figure 1 Device Image
(48 Pin 7×7×0.85mm^3 QFN Package)

2.0 Applications

Private mobile and military radios
Public safety handsets
Cellular infrastructure
LTE relays and microcells
Satellite terminals
Link 16, tactical data link
IFF

RoHS/REACH/Halogen Free Compliance

3.0 Description

The TS86436P is a 2nd Generation symmetrical reflective Single Pole Dual Throw (SP4T) switch designed for high power switching applications. The TS86436P covers 30MHz to 1320MHz bandwidth and provides low insertion loss, high isolation, and high linearity within a small package size. The TS86436P is a 200W-CW switch suitable for applications requiring low insertion loss, high isolation, and high linearity.

The TS86436P is packaged into a compact Quad Flat No lead (QFN) 7x7mm^2 48 leads plastic package.

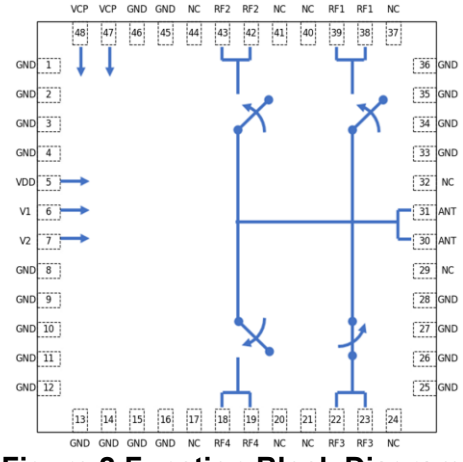


Figure 2 Function Block Diagram
(Top View)

4.0 Ordering Information

Table 1a Ordering Information

Device Part Number	Package Type	Eval Board Part Number
TS86436P	48 Pin 7×7×0.85mm QFN	Core part number
TS86436P-EVB	Evaluation Board	See Figure 3
TS86436PMTRPBF	330mm reel, 3 000 pcs	Ordering code for full reel

Table 1b Tape and Reel Information

Form	Quantity	Reel Diameter	Reel Width
Tape and Reel	3,000	13” (330mm)	18mm

5.0 Pin Description

Table 2 Pin Definition

Pin Number	Pin Name	Description
47,48	VCP	**Normal operation:** Connect PIN 47 and 48 together and connect a 1nF capacitor to GND on this node to improve switching time.
47	VCPin	**External -18V feed operation:** Connect external -18V source to this pin.
48	VCPout	**External -18V feed operation:** Output of the internal charge pump, leave to be NC
5	VDD	DC power supply
6	V1	Switch control input 1
7	V2	Switch control input 2
1,2,3,4,8,9,10,11,12,13,14,15,16,25,26,27,28, 33,34,35,36,45,46	NC	No internal connection, please connect to ground
17,20,21,24,29,32,37,40,41,44	NC	No internal connection. Do not connect to ground
38,39	RF1	RF port 1
42,43	RF2	RF port 2
22,23	RF3	RF port 3
18,19	RF4	RF port 4
30,31	ANT	Antenna port
49	GND	Ground thermal pad

Note: The backside ground (thermal) pad of the package must be grounded directly to the ground plane of PCB with multiple vias, and adequate heat sinking must be used to ensure proper operation and thermal management.

6.0 Absolute Maximum Ratings

Table 3 Absolute Maximum Ratings @T_A=+25°C Unless Otherwise Specified

Parameter	Symbol	Value	Unit
Electrical Ratings			
Power Supply Voltage	VDD	5.5	V
Storage Temperature Range	T_{st}	-55 to +125	°C
Operating Temperature Range	T_{op}	-40 to +85	°C
Maximum Junction Temperature	T_J	+140	°C
Maximum RF input power(30MHz).	RFx/ANT	54.0	dBm
Maximum RF input power(500MHz).	RFx/ANT	54.5	dBm
Maximum RF input power (VSWR 8:1).	RFx/ANT	49.0	dBm
Maximum RF input Peak Voltage.	RFx/ANT	160	V
Thermal Ratings			
Thermal Resistance (junction-to-case) – Bottom side	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance (junction-to-top)	$R_{\theta JT}$	30	°C/W
Soldering Temperature	T_{SOLD}	260	°C
ESD Ratings			
Human Body Model (HBM)	Level 1B	500 to <1000	V
Charged Device Model (CDM)	Level C3	≥1000	V
Moisture Rating			
Moisture Sensitivity Level	MSL	1	-

Attention:
Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.

7.0 Electrical Specifications

Table 4 Electrical Specifications @T_A=+25°C Unless Otherwise Specified; VDD=+3.3V; 50Ω Source/Load.

Parameter	Condition	Minimum	Typical	Maximum	Unit
Operating frequency		30		1320	MHz
Insertion loss, RFx	30 MHz		0.08	0.11	dB
	200 MHz		0.13	0.17	
	800 MHz (Matched)		0.34		
	1200 MHz (Matched)		0.39		
	1300 MHz (Matched)		0.45		
Isolation ANT-RFx	30 MHz		70		dB
	200 MHz		53		
	800 MHz (Matched)		41		
	1200 MHz (Matched)		33		
	1300 MHz (Matched)		33		
Return loss ANT, RFx	30 MHz		39		dB
	200 MHz		25		
	800 MHz (Matched)		18		
	1200 MHz (Matched)		20		
	1300 MHz (Matched)		15		
Harmonic distortion					
H2	30MHz, Pin=50dBm		88		dBc
H3	30MHz, Pin=50dBm		91		dBc
H2	800MHz, Pin=50dBm		75		dBc
H3	800MHz, Pin=50dBm		83		dBc
P0.1dB[1]	30MHz, CW		54		dBm
P0.1dB[1]	500MHz, CW		54		dBm
Peak P0.1dB[1]	30MHz, 1% duty cycle, 1 ms period		55.5		dBm
CP switching Noise	RBW = 1KHz		-140		dBm

Switching Time					
Rise time	10/90% of the RF value. CP=1nF to ground on VCP pin.		5	7	µs
Fall time	90/10% of the RF value. CP=1nF to ground on VCP pin.		1.7	2.2	µs
Switching ON time	50% ctrl to 10/90% of the RF value is settled. CP=1nF to ground on VCP pin.		13	17	µs
Switching OFF time	50% ctrl to 90/10% of the RF value is settled. CP=1nF to ground on VCP pin.		8	11	µs
DC					
Control voltage	Power Supply VDD	2.6	3.3	5.25	V
	All control pins high, V_{ih}	1.0	3.3	5.25	V
	All control pins low, V_{il}	-0.3		0.5	V
Control current	All control pins low, I_{il}		0		µA
	All control pins high, I_{ih}			7.5	µA
Current consumption, IDD	Active mode (VDD on)		160	260	µA
Current consumption, ICP	External VCP -18V, ICP		10	100	µA

Note:

[1] P0.1dB is a figure of merit.

[2] No external DC blocking capacitors required on RF pins unless DC voltage is applied on a RF pin.

[3] With external -18V feed, ICP current consumption depends on the switching frequency.

[4] TS86436P supports external voltage supply to VCPin to increase pulse repetition rate fPRR. With external voltage supply, fPRR can be increased at least to support pulse repetition rate more than 20kHz, in some cases even up to 100kHz. In order to use external voltage, it is mandatory to supply first VDD, have a delay of 1ms and then apply-18V to VCPin. Shutdown should be in opposite order. In this case, please use pinout **External -18V feed operation.**

8.0 Switch Truth Table

Table 5. Switch Truth Table

V1	V2	Active RF Path
0	0	ANT-RF1 ON
1	0	ANT-RF2 ON
0	1	ANT-RF3 ON
1	1	ANT-RF4 ON

Attention:
[1] VDD should be applied first before V1 and V2, otherwise may cause damage to the device.
[2] There are internal pull-downs to ground on both V1 and V2 control pins, the state at start-up without any control voltage applied will be ANT-RF1 ON.

9.0 Schematic and Evaluation Board

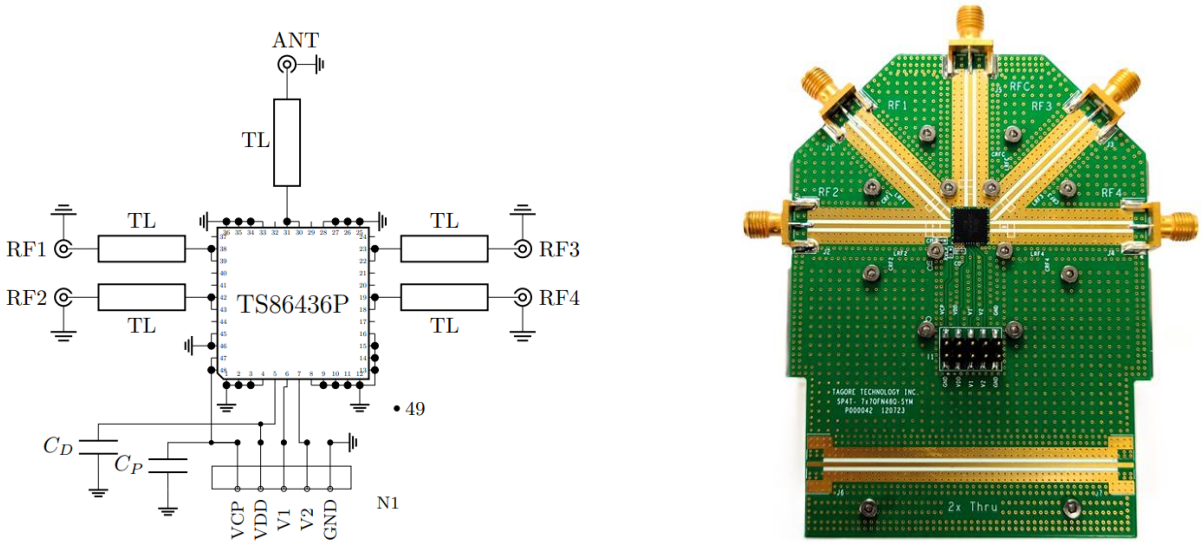


Figure 3 Evaluation Board and Schematic.

Attention:
[1] 49 refers to the center pad of the device. Multiple Plugged through hole vias should be added on this ground pad and adequate heat sinking should be used.
[2] The purpose of connection between VCP and connector N1 is to monitor VCP, do not apply external voltage to VCP.

10.0 Typical Characteristics – Unmatched (<500 MHz)

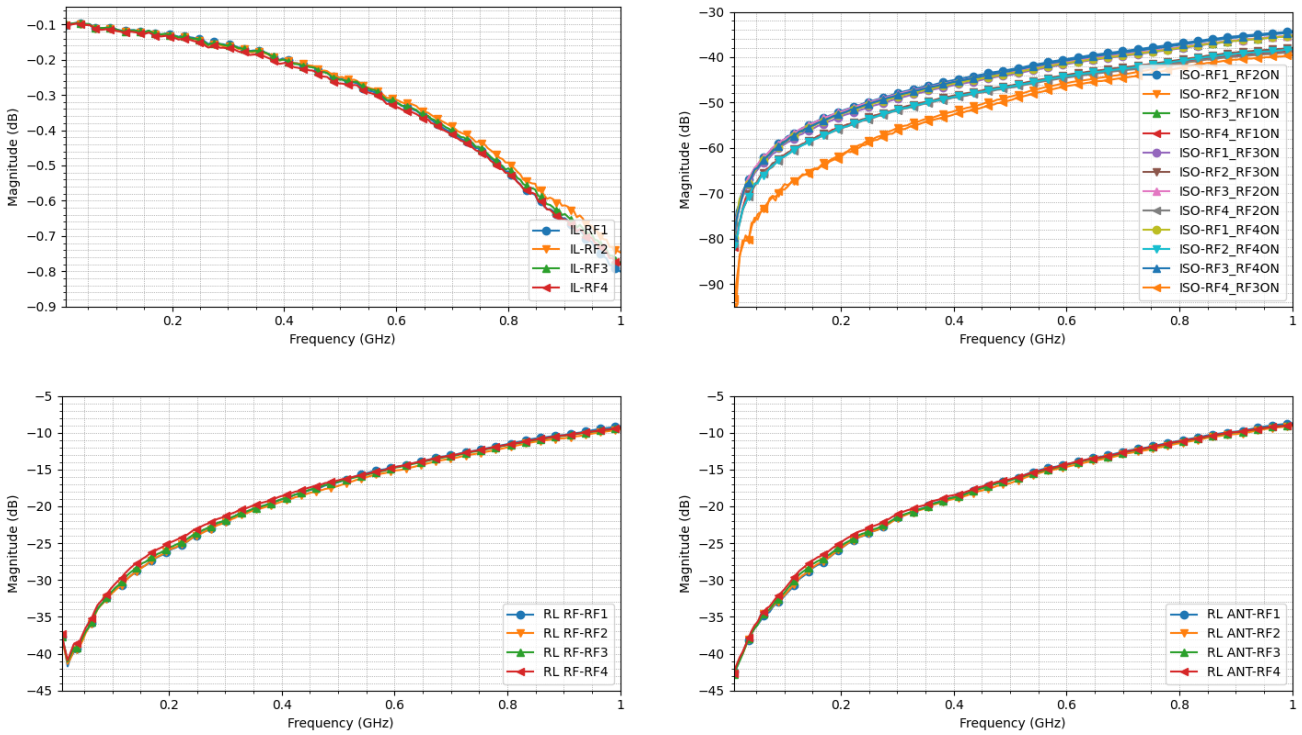


Figure 4a Typical characteristics

10.1 Typical Characteristics – Matched (760 MHz – 870 MHz)

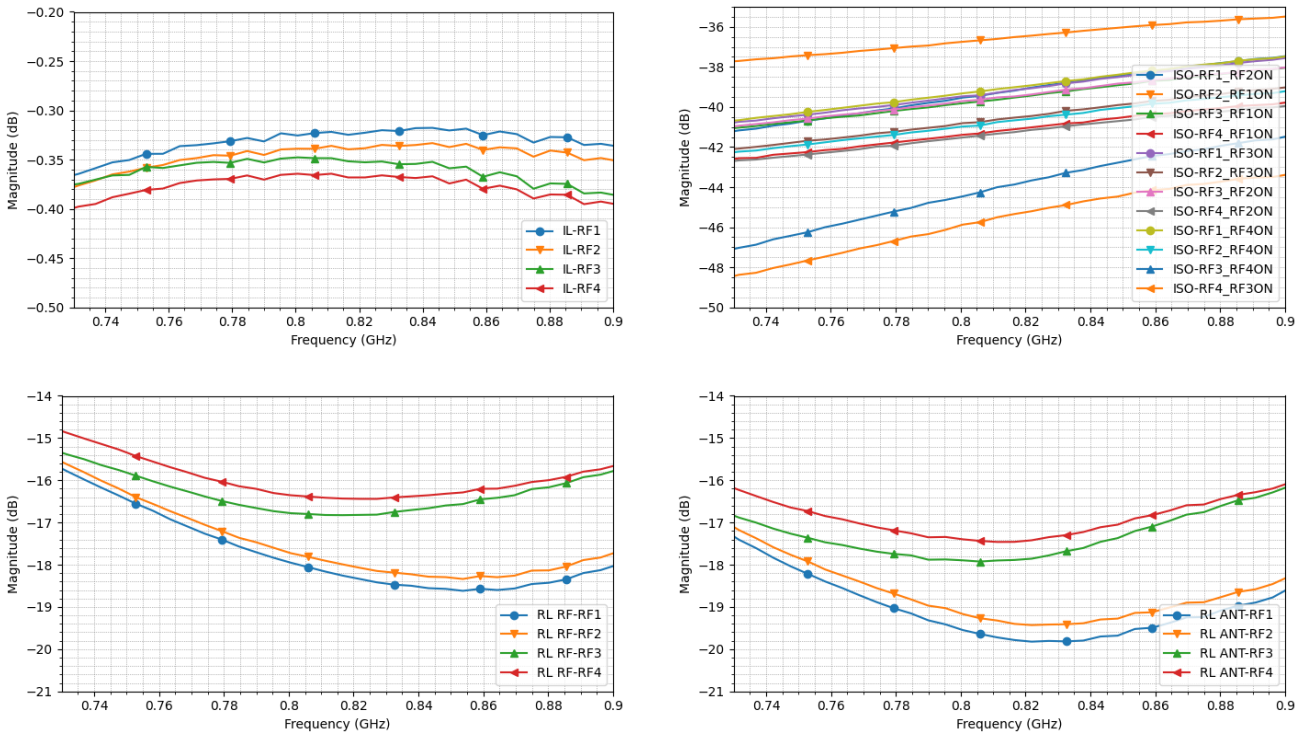


Figure 4b Typical characteristics (760 MHz – 870 MHz)

10.2 Typical Characteristics – Matched (1100 MHz – 1200 MHz)

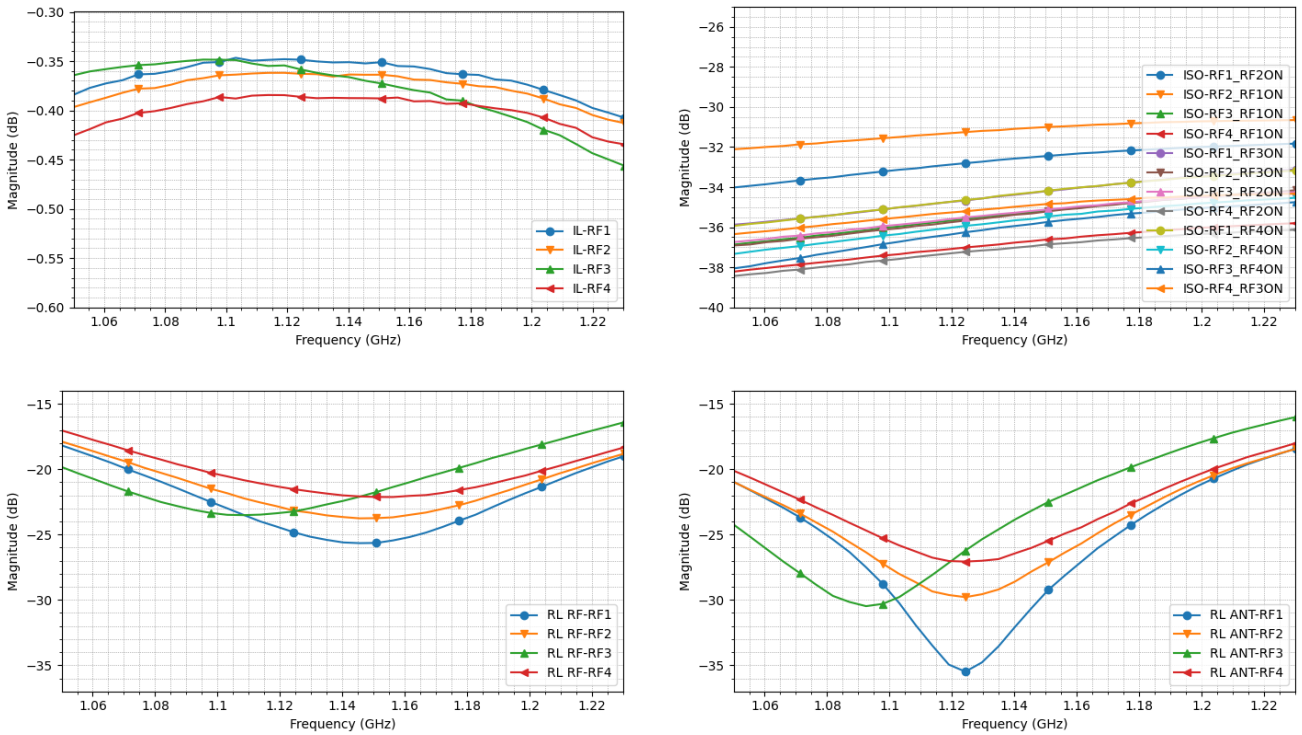


Figure 4c Typical characteristics (1100 MHz – 1200 MHz)

10.3 Typical Characteristics – Matched (1200 MHz – 1320 MHz)

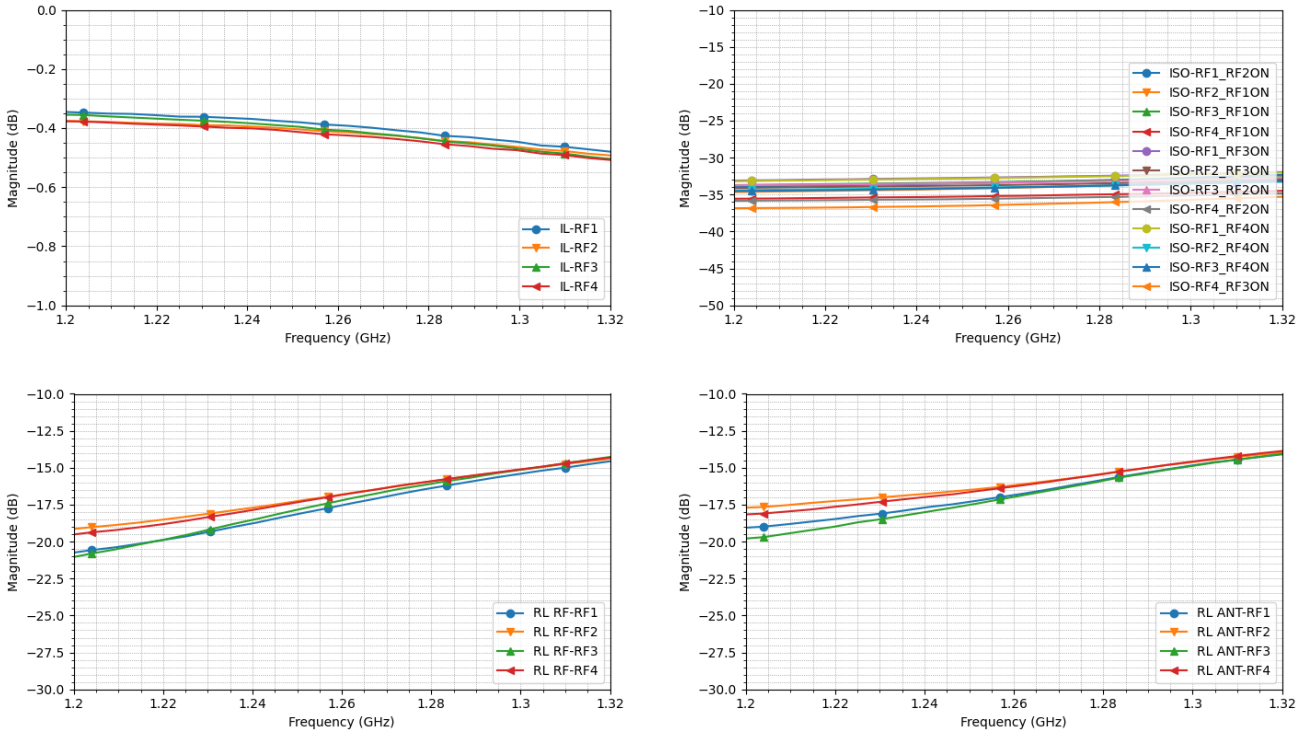


Figure 4d Typical characteristics (1200 MHz – 1320 MHz)

Table 6.1 Bill of Materials – Matching* (<500 MHz)

Component	Part Number	Description	Notes
C_P	GRM155R61E104KA87D	Ceramic capacitor, 0.1 µF, 25 V, ±10%.	
C_D	GRM155R71H103KA88	Ceramic capacitor, 10 nF, 50 V, ±15%.	

* For additional details, please contact the TagoreTech support.

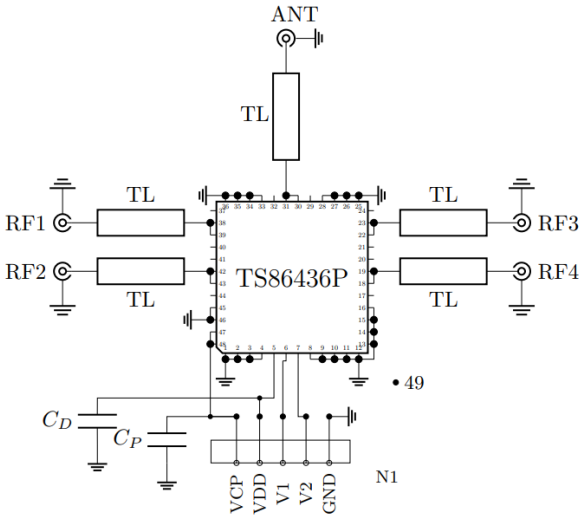


Figure 5a. Unmatched circuit schematic.

Table 6.2 Bill of Materials – Matching* (760 MHz – 870 MHz)

Component	Part Number	Description	Notes
C_P	GRM155R61E104KA87D	Ceramic capacitor, 0.1 µF, 25 V, ±10%.	
C_D	GRM155R71H103KA88	Ceramic capacitor, 10 nF, 50 V, ±15%.	
L_{1a}	0908SQ-12N_L_	Air core chip inductor, 12.1 nH, ± 5%.	
L_{2a}	0908SQ-12N_L_	Air core chip inductor, 12.1 nH, ± 5%.	
L_{3a}	0908SQ-12N_L_	Air core chip inductor, 12.1 nH, ± 5%.	
L_{4a}	0908SQ-12N_L_	Air core chip inductor, 12.1 nH, ± 5%.	
T_{1a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{2a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{3a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{4a}	1 mm	PCB transmission line length.	From the IC-reference plane.

* For additional details, please contact the TagoreTech support.

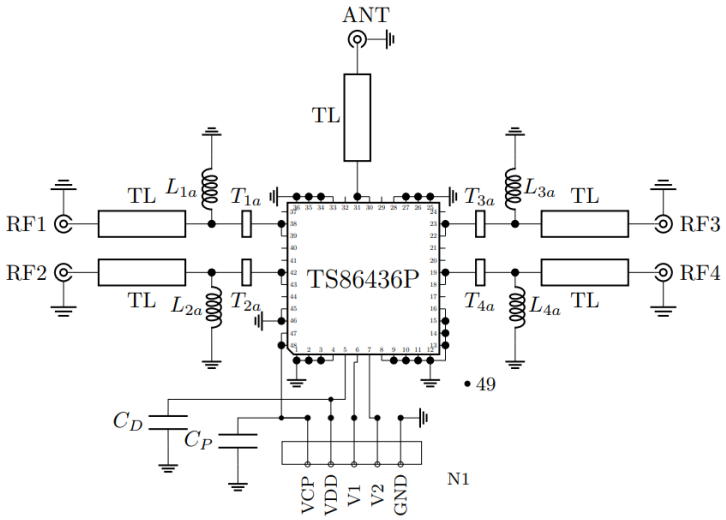


Figure 5b. 760 MHz – 870 MHz circuit schematic.

Table 6.3 Bill of Materials – Matching* (1100 MHz – 1200 MHz)

Component	Part Number	Description	Notes
C_P	GRM155R61E104KA87D	Ceramic capacitor, 0.1 µF, 25 V, ±10%.	
C_D	GRM155R71H103KA88	Ceramic capacitor, 10 nF, 50 V, ±15%.	
C_{1a}	0603N100JW251	Ceramic capacitor, 10 pF, 250 V, ±5%.	
C_{2a}	0603N100JW251	Ceramic capacitor, 10 pF, 250 V, ±5%.	
C_{3a}	0603N100JW251	Ceramic capacitor, 10 pF, 250 V, ±5%.	
C_{4a}	0603N100JW251	Ceramic capacitor, 10 pF, 250 V, ±5%.	
L_{1a}	0806SQ-6N0_L_	Air core chip inductor, 6.0 nH, ± 5%.	
L_{2a}	0806SQ-6N0_L_	Air core chip inductor, 6.0 nH, ± 5%.	
L_{3a}	0806SQ-6N0_L_	Air core chip inductor, 6.0 nH, ± 5%.	
L_{4a}	0806SQ-6N0_L_	Air core chip inductor, 6.0 nH, ± 5%.	
T_{1a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{2a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{3a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{4a}	1 mm	PCB transmission line length.	From the IC-reference plane.

* For additional details, please contact the TagoreTech support.

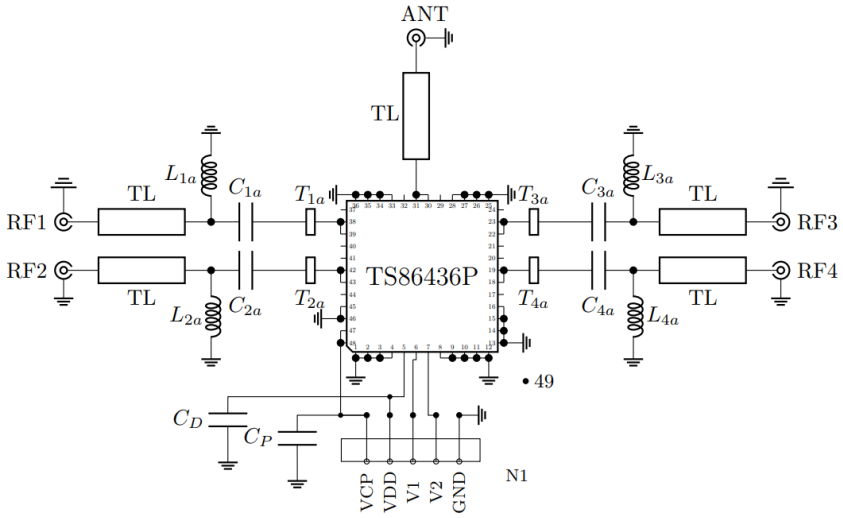


Figure 5c. 1100 MHz – 1200 MHz circuit schematic.

Table 6.4 Bill of Materials – Matching* (1200 MHz – 1320 MHz)

Component	Part Number	Description	Notes
C_P	GRM155R61E104KA87D	Ceramic capacitor, 0.1 µF, 25 V, ±10%.	
C_D	GRM155R71H103KA88	Ceramic capacitor, 10 nF, 50 V, ±15%.	
C_{0a}	0603N100JW251	Ceramic capacitor, 10 pF, 250 V, ±5%.	
L_{0a}	A02T_L_	Mini Spring Air Core Inductor, 5.0 nH, ± 5%.	
T_{0a}	1 mm	PCB transmission line length.	From the IC-reference plane.
T_{0b}	0.5 mm	PCB transmission line length.	

* For additional details, please contact the TagoreTech support.

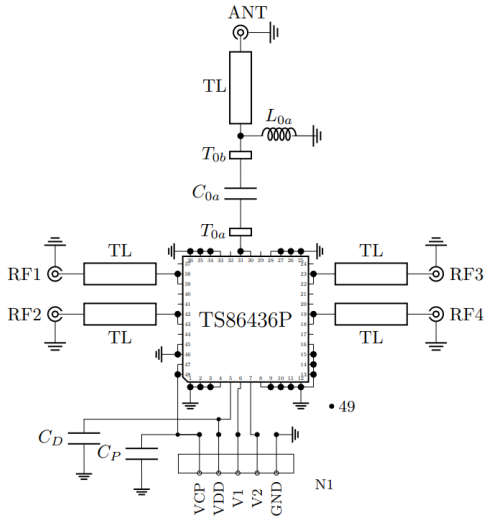


Figure 5d. 1200 MHz – 1320 MHz circuit schematic.

11.0 Device Package Information

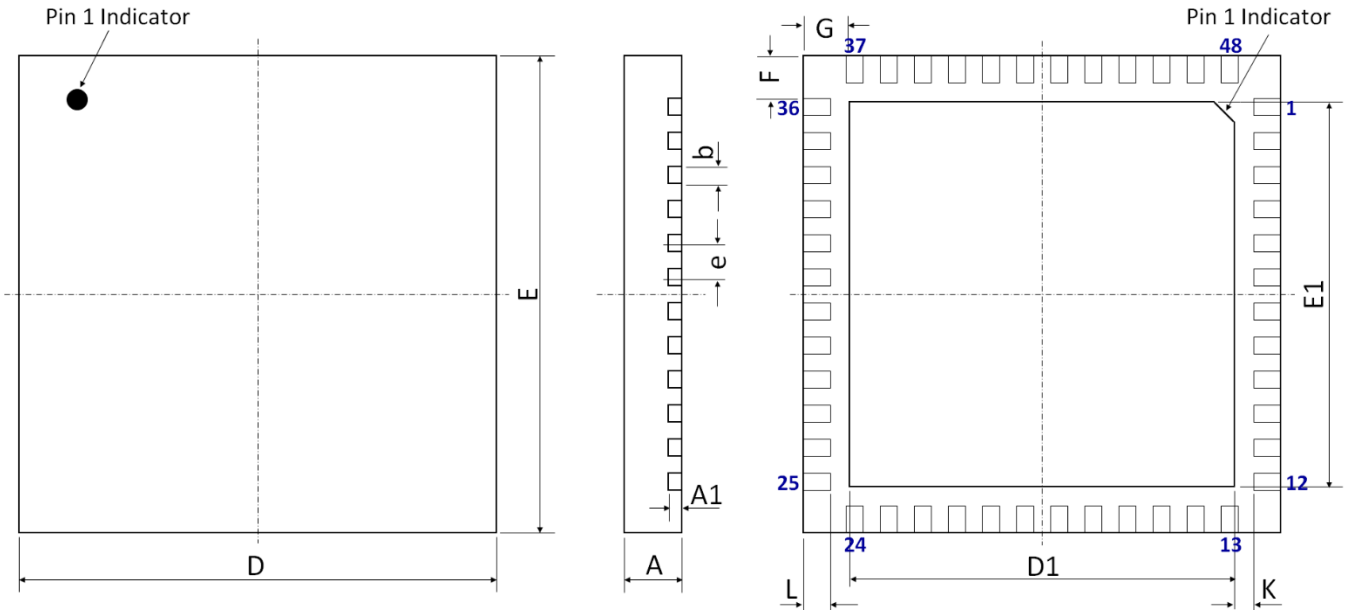


Figure 6 Device Package Drawing
(All dimensions are in mm)

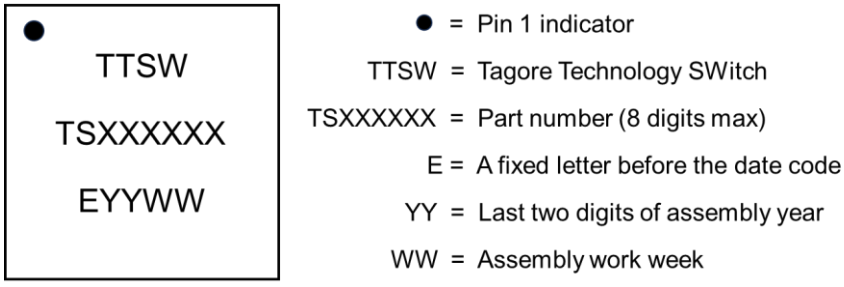
Table 7 Device Package Dimensions

Dimension	**Value** (mm)	**Tolerance** (mm)	**Dimension**	**Value** (mm)	**Tolerance** (mm)
A	0.85	±0.05	E	7.00 BSC	±0.05
A1	0.203	±0.02	E1	5.65	±0.06
b	0.25	+0.05/-0.07	F	0.625	±0.05
D	7.00 BSC	±0.05	G	0.625	±0.05
D1	5.65	±0.06	L	0.40	±0.05
e	0.50 BSC	±0.05	K	0.275	±0.05

Note: Lead finish: Pure Sn without underlayer; Thickness: 7.5μm ~ 20μm (Typical 10μm ~ 12μm)

Attention:
Please refer to application notes *TN-001* and *TN-002* at http://www.tagoretech.com for PCB and soldering related guidelines.

Top Marking Specifications:



12.0 PCB Land Design

Guidelines:

[1] 4-layer PCB is recommended.
[2] Via diameter is recommended to be 0.3mm to prevent solder wicking inside the vias.
[3] Thermal vias shall only be placed on the center pad.
[4] The maximum via number for the center pad is 11(X)×11(Y)=121.

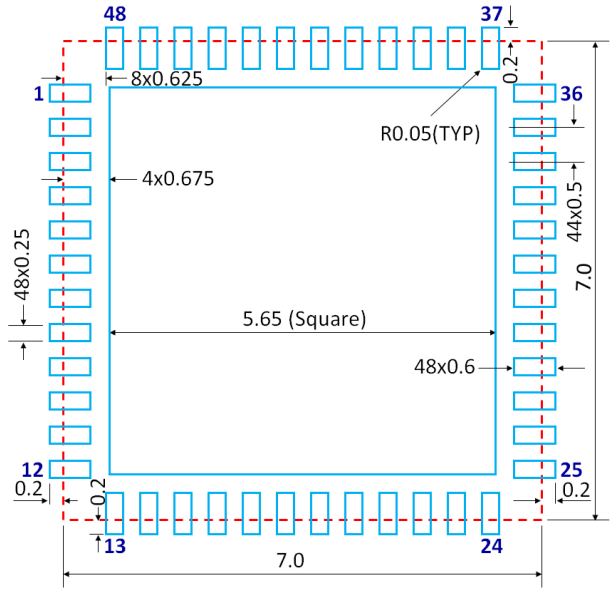
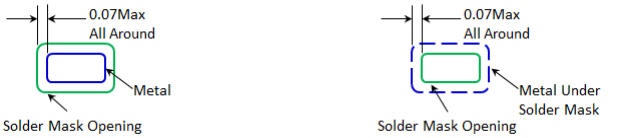


Figure 7 PCB Land Pattern
(Dimensions are in mm)



Non-Solder Mask Defined (Preferred)

Solder Mask Defined

Figure 8 Solder Mask Pattern
(Dimensions are in mm)

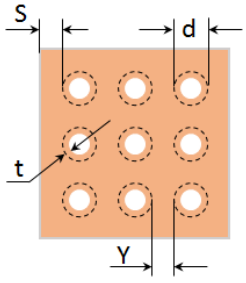


Figure 9 Thermal Via Pattern
(Recommended Values: S≥0.15mm; Y≥0.20mm; d=0.3mm; Plating Thickness t=25μm or 50μm)

13.0 PCB Stencil Design

Guidelines:

[1] Laser-cut, stainless steel stencil is recommended with electro-polished trapezoidal walls to improve the paste release.

[2] Stencil thickness is recommended to be 125μm.

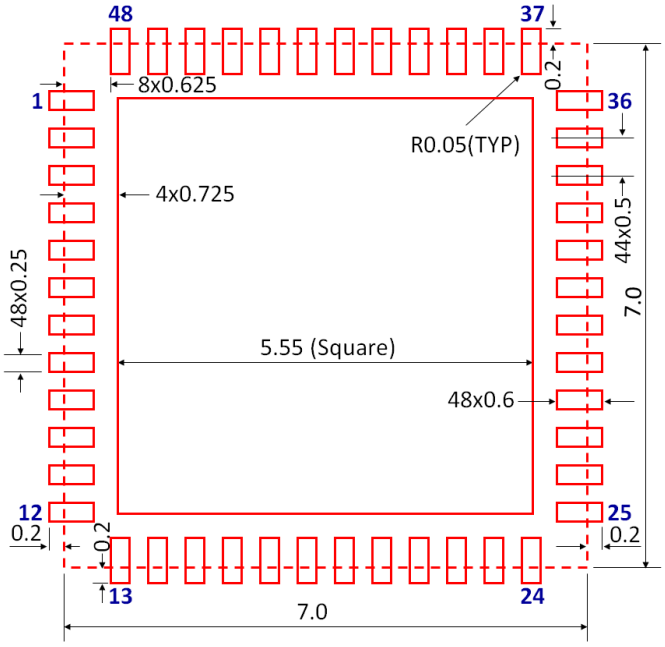


Figure 10 Stencil Openings
(Dimensions are in mm)

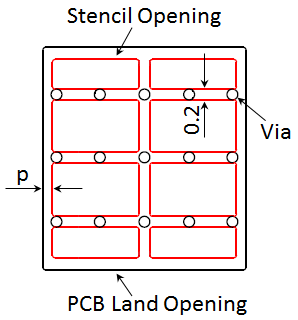


Figure 11 Stencil Openings Shall not Cover Via Areas If Possible
(Dimensions are in mm)

14.0 Tape and Reel Information

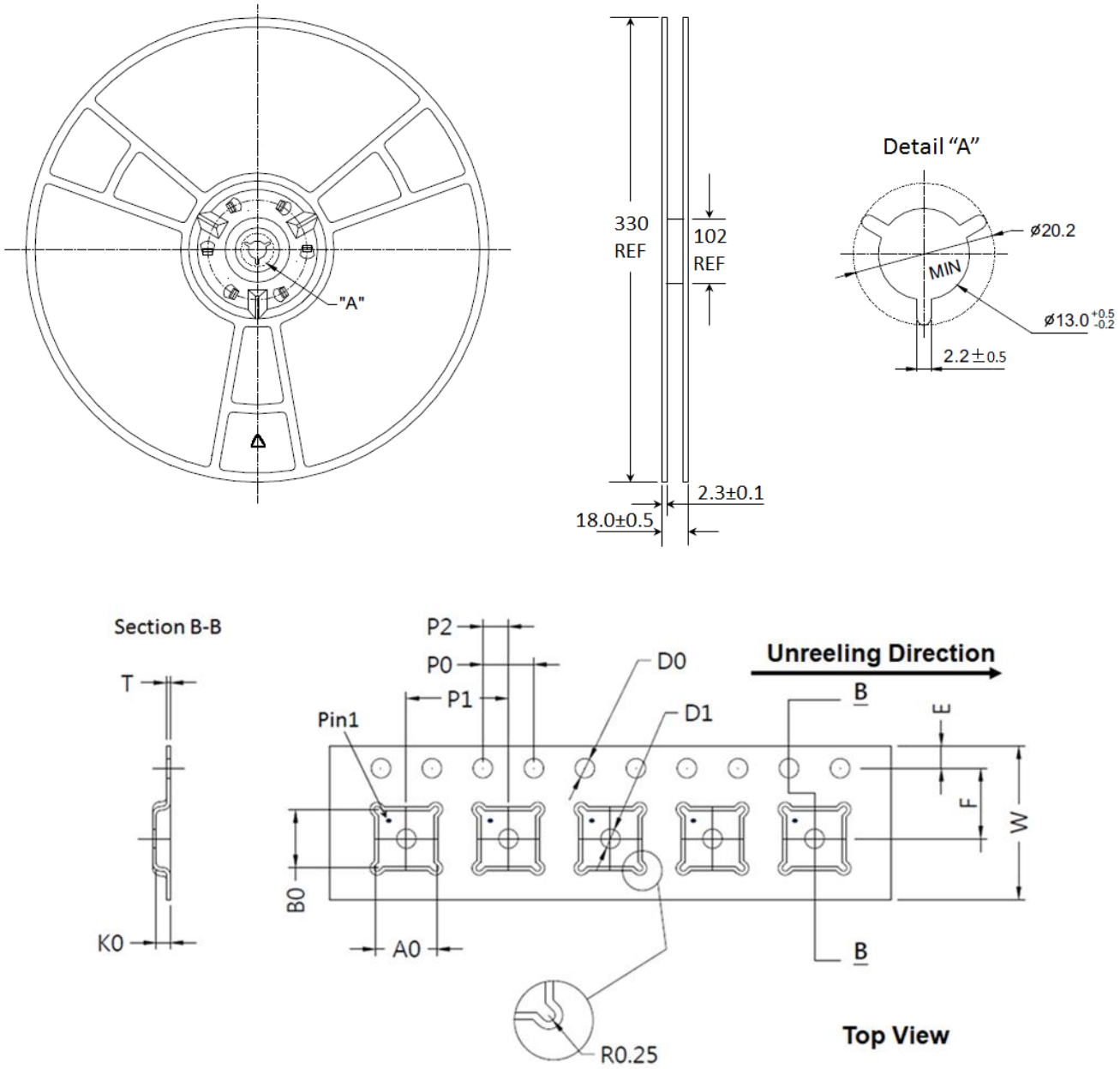


Figure 12 Tape and Reel Drawing

Table 8 Tape and Reel Dimensions

Dimension	**Value** (mm)	**Tolerance** (mm)	**Dimension**	**Value** (mm)	**Tolerance** (mm)
A0	7.35	±0.10	K0	1.10	±0.10
B0	7.35	±0.10	P0	4.00	±0.10
D0	1.50	+0.10/-0.00	P1	8.00	±0.10
D1	1.50	+0.10/-0.00	P2	2.00	±0.05
E	1.75	±0.10	T	0.30	±0.05
F	5.50	±0.05	W	12.00	±0.30

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